

TRADEMARK ASSIGNMENT

Electronic Version v1.1
 Stylesheet Version v1.1

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| SUBMISSION TYPE: | NEW ASSIGNMENT |
| NATURE OF CONVEYANCE: | Termination of Debtor-in-Possession Intellectual Property Security Agreement |

CONVEYING PARTY DATA

| Name | Formerly | Execution Date | Entity Type |
|------------------------|----------|----------------|-------------------|
| Wells Fargo Bank, N.A. | | 08/24/2010 | COMPANY: DELAWARE |

RECEIVING PARTY DATA

| | |
|------------------------|-------------------------|
| Name: | EPV Solar, Inc. |
| Street Address: | 8 Marlen Drive |
| City: | Robbinsville |
| State/Country: | NEW JERSEY |
| Postal Code: | 08690 |
| Entity Type: | CORPORATION: NEW JERSEY |

| | |
|------------------------|------------------------|
| Name: | EPV Solar Germany GmbH |
| Street Address: | 8 Marlen Drive |
| City: | Robbinsville |
| State/Country: | NEW JERSEY |
| Postal Code: | 08690 |
| Entity Type: | COMPANY: GERMANY |

PROPERTY NUMBERS Total: 3

| Property Type | Number | Word Mark |
|----------------------|---------|-------------|
| Registration Number: | 2614699 | EPV |
| Registration Number: | 2612208 | EPV-40 |
| Registration Number: | 3121710 | EPV OUTSIDE |

CORRESPONDENCE DATA

Fax Number: (617)856-8201
Correspondence will be sent via US Mail when the fax attempt is unsuccessful.
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CH \$90.00 2614699

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Address Line 2: Brown Rudnick LLP
Address Line 4: Boston, MASSACHUSETTS 02111

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|-------------------------|--------------------|
| ATTORNEY DOCKET NUMBER: | 28869/1 |
| NAME OF SUBMITTER: | Mark S. Leonardo |
| Signature: | /Mark S. Leonardo/ |
| Date: | 09/13/2010 |

Total Attachments: 6

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**TERMINATION OF DEBTOR-IN-POSSESSION INTELLECTUAL PROPERTY SECURITY
AGREEMENT
(PATENTS & TRADEMARKS)**

This Termination of Debtor-in-Possession Intellectual Property Security Agreement, dated as of August 27, 2010, is executed by WELLS FARGO BANK, N.A., as Agent, having a place of business at 45 Broadway, 14th Floor, New York, New York 10006 as Agent (the "Agent") for itself and the Lenders, for the purpose of releasing the security interest of the Agent in the Intellectual Property (as defined below) owned by EPV SOLAR, INC., a New Jersey corporation and EPV SOLAR GERMANY GMBH, a German Company (the "Grantors").

Recitals

WHEREAS, the Agent was granted by Grantors, a security interest in the Patents and Trademarks of the Grantors, listed on **Schedule A** hereto (collectively, the "Intellectual Property") pursuant to that certain Debtor-in-Possession Intellectual Property Security Agreement dated as of March 25, 2010 and recorded in the United States Patent and Trademark Office on March 26, 2010 at Reel 024140, Frame 0472 and at Reel 004175, Frame 0166 respectively;

WHEREAS, Agent has agreed to terminate and release its security interest in the Intellectual Property;
and

WHEREAS, Agent wishes to provide a document suitable for recording in the United States Patent and Trademark Office for purposes of recording the termination and release of the security interest in and to the Intellectual Property previously granted by Grantors to Agent.

NOW, THEREFORE, in consideration of the premises and other good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, Agent hereby agrees as follows:

The Agent hereby terminates and releases the Agent's security interest in the Intellectual Property as set forth at the Reel and Frame numbers referenced above.

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WELLS FARGO BANK, N.A., as Agent

By: 

Title: Vice President

SCHEDULE A

Trademarks

| MARK | OWNER | COUNTRY | APPL NO | CLASS | FILED | REG NO | REG DT | STATUS |
|-------------|-----------------|---------|------------|-------|---------|-----------|---------|------------|
| EPV | EPV Solar, Inc. | US | 76/240,598 | 9 | 4/16/01 | 2,614,699 | 9/03/82 | Canceled |
| EPV-40 | EPV Solar, Inc. | US | 76/240,599 | 9 | 4/16/01 | 2,612,208 | 8/27/02 | Canceled |
| EPV Outside | EPV Solar, Inc. | US | 76/450,062 | 9 | 7/13/04 | 3,121,710 | 7/25/06 | Registered |

U.S. Patents

| Patent No./Issue Date | Publication No./ Publication Date | Title |
|-------------------------|--------------------------------------|--|
| 7,652,209 01-26-2010 | 2006-0144436 07-06-2006 | METHOD OF JUNCTION FORMATION FOR CIGS PHOTOVOLTAIC DEVICES |
| 7,235,160 06-26-2007 | 2005-0029088 02-10-2005 | HOLLOW CATHODE SPUTTERING APPARATUS AND RELATED METHOD |
| 7,019,208 03-28-2006 | 2003-0102023 06-05-2003 | METHOD OF JUNCTION FORMATION FOR CIGS PHOTOVOLTAIC DEVICES |
| 6,660,538 12-09-2003 | 2003-0082834 05-01-2003 | NON-CONTACTING DEPOSITION CONTROL OF CHALCOPYRITE THIN FILMS |

Patent Applications Filed and Pending

| Serial No./Filing Date | Publication No./ Publication Date | Title |
|--------------------------|--------------------------------------|--|
| 12/557,389 09-10-2009 | N/A | MOUNTING SYSTEMS FOR PHOTOVOLTAIC MODULES |
| 12/488,218 TBD | N/A | METHOD FOR FABRICATING A DOPED AND/OR ALLOYED SEMICONDUCTOR |
| 12/466,141 05-14-2009 | 2009/0301551 12-10-2009 | SILICON FILM DEPOSITION METHOD UTILIZING A SILENT ELECTRIC DISCHARGE AND AN ACTIVE SPECIES |
| 12/466,137 05-14-2009 | 2009/0293943 12-03-2009 | SILICON FILM DEPOSITION METHOD UTILIZING A SILENT ELECTRIC DISCHARGE |
| 12/422,004 04-10-2009 | 2009/0255582 10-15-2009 | METHODS OF DRYING GLASS FOR PHOTOVOLTAIC APPLICATIONS |
| 12/410,297 3-24-2009 | 2009/0235987 09-14-2009 | CHEMICAL TREATMENTS TO ENHANCE PHOTOVOLTAIC PERFORMANCE OF CIGS |
| 12/395,889 03-02-2009 | N/A | INSULATED GLASS UNIT WITH INTEGRATED MINI-JUNCTION BOX |

| Serial No./Filing Date | Publication No./ Publication Date | Title |
|--------------------------|-----------------------------------|---|
| 12/127,470 05-27-2008 | 2008/0308411 12-18-2008 | METHOD AND PROCESS FOR DEPOSITION OF TEXTURED ZINC OXIDE THIN FILMS |
| 11/768,652 06-26-2007 | 2007/0256926 11-08-2007 | HOLLOW CATHODE SPUTTERING APPARATUS AND RELATED METHOD |
| 11/275,079 12-08-2005 | 2006/0118406 06-08-2006 | SPUTTERED TRANSPARENT CONDUCTIVE FILMS |
| 61/097,769 09-17-08 | N/A | LARGE BATCH PRODUCTION OF THIN PHOTOVOLTAIC MODULES |

Non-U.S. Patent Applications

| Patent No./Issue Date | Publication No./ Publication Date | Title | National Filing Due Date (31 Month) |
|---------------------------------|-----------------------------------|---|-------------------------------------|
| PCT/US2009/001318 03-02-2009 | WO 2009/108385 09-03-2009 | INSULATED GLASS UNIT WITH INTEGRATED MINI-JUNCTION BOX | 09-28-2010 |
| PCT/US2009/001815 03-24-2009 | WO 2009/120302 10-01-2009 | CHEMICAL TREATMENTS TO ENHANCE PHOTOVOLTAIC PERFORMANCE OF CIGS | 10-24-2010 |